



25 - 3000 MHz

FRACTIONAL-N PLL WITH INTEGRATED VCO

RoHS

Features

- RF Bandwidth: 25 - 3000 MHz
- Maximum Phase Detector Rate 100 MHz
- Ultra Low Phase Noise -110 dBc/Hz in Band Typ.
- Figure of Merit (FOM) -227 dBc/Hz

Typical Applications

- Cellular/4G Infrastructure
- Repeaters and Femtocells
- Communications Test Equipment
- CATV Equipment

- · Phased Array Applications DDS Replacement
 - Very High Data Rate Radios
 - Tunable Reference Source for Spurious-Free Performance
- **Functional Diagram** LD_SDO VCCPD VCCPS VCCHF BIAS N/C 2 Z N N SCK S 40 39 38 37 36 35 34 33 32 31 30 AVDD 1 SEN E١ 2 29 N/C RF_P CONTROL 28 VPPCP 3 EN RF_N 27 CP 4 СР VCC1 MODULATOR ÷1,2,4,6...62 CAL 26 N/C 5 N/C 25 N/C 6 VCC2 ÷Ν VDDLS 7 24 N/C VCO PFD 23 N/C 8 VTUNE ÷R N/C 9 22 N/C 21 RVDD 10 N/C 15 13 16 17 18 19 11 12 14 20 PACKAGE N/C N/C N/C N/C XREFP N/c N/C N/C CEN DVDD3V BASE GND

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

<180 fs RMS Jitter

v03.0512

- 24-bit Step Size, Resolution 3 Hz typ
- Exact Frequency Mode
- Built in Digital Self Test
- 40 Lead 6x6 mm SMT Package: 36 mm²



HMC830* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

HMC830LP6GE Evaluation Board

DOCUMENTATION

Application Notes

- Frequency Hopping with Hittite PLLVCOs Application
 Note
- PLL & PLLVCO Serial Programming Interface Mode Selection Application Note
- Power-Up & Brown-Out Design Considerations for RF PLL +VCO Products Application Note
- Wideband RF PLL+VCO and Clock Generation Products FAQs

Data Sheet

• HMC830 Data Sheet

User Guides

 PLLs with Integrated VCO - RF Applications Product & Operating Guide

TOOLS AND SIMULATIONS \square

- ADIsimFrequency Planner Tool
- ADIsimPLL[™]
- HMC830 IBIS Model

REFERENCE MATERIALS

Quality Documentation

- HMC Legacy PCN: LP6CE and LP6GE QFN Alternate assembly source
- Package/Assembly Qualification Test Report: LP6, LP6C, LP6G (QTR: 2014-00368)
- Semiconductor Qualification Test Report: BiCMOS-A (QTR: 2013-00235)

Technical Articles

- Low Cost PLL with Integrated VCO Enables Compact LO Solutions
- Wideband Phase-Locked Loops with Integrated Voltage Controlled Oscillators

DESIGN RESOURCES

- HMC830 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC830 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK

Submit feedback for this data sheet.



FRACTIONAL-N PLL WITH INTEGRATED VCO 25 - 3000 MHz

General Description

The HMC830LP6GE is a low noise, wide band, Fractional-N Phase-Locked-Loop (PLL) that features an integrated Voltage Controlled Oscillator (VCO) with a fundamental frequency of 1500 MHz - 3000 MHz, and an integrated VCO Output Divider (divide by 1/2/4/6.../60/62), that together allow the HMC830LP6GE to generate frequencies from 25 MHz to 3000 MHz. The integrated Phase Detector (PD) and delta-sigma modulator, capable of operating at up to 100 MHz, permit wider loop-bandwidths with excellent spectral performance.

v03.0512

The HMC830LP6GE features industry leading phase noise and spurious performance, across all frequencies, that enable it to minimize blocker effects, and improve receiver sensitivity and transmitter spectral purity. The superior noise floor (< -170 dBc/Hz) makes the HMC830LP6GE an ideal source for a variety of applications - such as; LO for RF mixers, a clock source for high-frequency data-converters, or a tunable reference source for ultra-low spurious applications.

Additional features of the HMC830LP6GE include RF output power control from 0 to 9 dB (3 dB steps), output Mute function, and a delta-sigma modulator Exact Frequency Mode which enables users to generate output frequencies with 0 Hz frequency error.

For theory of operation and register map refer to the "PLLs with Integrated VCOs - RF VCOs Operating Guide". To view the Operating Guide, please visit www.hittite.com and choose HMC830LP6GE from the "Search by Part Number" pull down menu.

Parameter	Condition	Min.	Тур.	Max.	Units
RF Output Characteristics					
Output Frequency		25		3000	MHz
VCO Frequency at PLL Input		1500		3000	MHz
RF Output Frequency at f _{VCO}		1500		3000	MHz
Output Power					
RF Output Power at f _{VCO} = 2000 MHz Across All Frequencies see Figure 10	Broadband Matched Internally [1]	4.5	6	7.5	dBm
Output Power Control	3 dB Steps	7		9	dB
Harmonics					
fo Mode at 2 GHz	2nd / 3rd / 4th		-20/-29/-45		dBc
fo/2 Mode at 2GHz/2 = 1 GHz	2nd / 3rd / 4th		-23/-15/-35		dBc
fo/30 Mode at 3 GHz/30 = 100 MHz	2nd / 3rd / 4th		-25/-10/-33		dBc
fo/62 Mode at 1550 MHz/62 = 25 MHz	2nd / 3rd / 4th		-17/-8/-21		dBc
VCO Output Divider					
VCO RF Divider Range	1,2,4,6,8,,62	1		62	
PLL RF Divider Characteristics					
19-Bit N-Divider Range (Integer)	Max = 2 ¹⁹ - 1	16		524,287	
19-Bit N-Divider Range (Fractional)	Fractional nominal divide ratio varies (-3 / +4) dynamically max	20		524,283	
REF Input Characteristics					
Max Ref Input Frequency				350	MHz
Ref Input Voltage	AC Coupled [2]	1	2	3.3	Vp-p
Ref Input Capacitance				5	pF

Electrical Specifications

VPPCP, VDDLS, VCC1, VCC2 = 5 V; RVDD, AVDD, DVDD3V, VCCPD, VCCHF, VCCPS = 3.3 V Min and Max Specified across Temp -40 °C to 85 °C

[2] Measured with 100 Ω external termination. See Hittite PLL w/ Integraged VCOs Operating Guide Reference Input Stage section for more details.

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.





Electrical Specifications (Continued)

v03.0512

Parameter	Condition	Min.	Тур.	Max.	Units
14-Bit R-Divider Range		1		16,383	
Phase Detector (PD) [3]				•	
PD Frequency Fractional Mode B	[4]	DC		100	MHz
PD Frequency Fractional Mode A (and Register 6 [17:16] = 11)		DC		80	MHz
PD Frequency Integer Mode		DC		125	MHz
Charge Pump				•	
Output Current		0.02		2.54	mA
Charge Pump Gain Step Size			20		μA
PD/Charge Pump SSB Phase Noise	50 MHz Ref, Input Referred				
1 kHz			-143		dBc/Hz
10 kHz	Add 1 dB for Fractional		-150		dBc/Hz
100 kHz	Add 3 dB for Fractional		-153		dBc/Hz
Logic Inputs			-		
Vsw		40	50	60	% DVDD
Logic Outputs			-		
VOH Output High Voltage			DVDD		V
VOL Output Low Voltage			0		V
Output Impedance		100		200	Ω
Maximum Load Current				1.5	mA
Power Supply Voltages					
3.3 V Supplies	AVDD, VCCHF, VCCPS, VCCPD, RVDD,DVDD	3.0	3.3	3.5	v
5 V Supplies	VPPCP, VDDLS, VCC1, VCC2	4.8	5	5.2	V
Power Supply Currents					
+5V Analog Charge Pump	VPPCP, VDDLS		8		mA
15V VCO Corp and VCO Buffar	fo/1 Mode VCC2		105		mA
+5V VCO Core and VCO Buffer	fo/N Mode VCC2		80		mA
+5V VCO Divider and RF/PLL Buffer	fo/1 Mode VCC1		25		mA
	fo/N Mode VCC1	80		100	mA
+3.3V	AVDD, VCCHF, VCCPS, VCCPD, RVDD, DVDD3V		52		mA
Power Down - Crystal Off	Reg 01h=0, Crystal Not Clocked		10		μA
Power Down - Crystal On, 100 MHz	Reg 01h=0, Crystal Clocked 100 MHz		10	30	mA
Power on Reset					
Typical Reset Voltage on DVDD			700		mV
Min DVDD Voltage for No Reset		1.5			V
Power on Reset Delay			250		μs
VCO Open Loop Phase Noise at fo @ 2 GH	2				
10 kHz Offset			-86		dBc/Hz

[3] Slew rate of greater or equal to 0.5 ns/V is recommended, see <u>PLL with Integrated RF VCOs Operating Guide</u> for more details. Frequency is guaranteed across process voltage and temperature from -40 °C to 85 °C.

[4] This maximum phase detector frequency can only be achieved if the minimum N value is respected. eg. In the case of fractional feedback mode, the maximum PFD rate = fvco/20 or 100 MHz, whichever is less.

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.





FRACTIONAL-N PLL WITH INTEGRATED VCO 25 - 3000 MHz

Electrical Specifications (Continued)

v03.0512

Parameter	Condition	Min.	Тур.	Max.	Units
100 kHz Offset			-116		dBc/Hz
1 MHz Offset			-141		dBc/Hz
10 MHz Offset			-162		dBc/Hz
100 MHz Offset			-171		dBc/Hz
VCO Open Loop Phase Noise at fo @ 2 G	Hz/2 = 1 GHz				
10 kHz Offset			-92		dBc/Hz
100 kHz Offset			-122		dBc/Hz
1 MHz Offset			-147		dBc/Hz
10 MHz Offset			-165		dBc/Hz
100 MHz Offset			-165		dBc/Hz
VCO Open Loop Phase Noise at fo @3 GH	łz/30 = 100 MHz				
10 kHz Offset			-112		dBc/Hz
100 kHz Offset			-142		dBc/Hz
1 MHz Offset			-165		dBc/Hz
10 MHz Offset			-168		dBc/Hz
100 MHz Offset			-171		dBc/Hz
Figure of Merit					
Floor Integer Mode	Normalized to 1 Hz		-230		dBc/Hz
Floor Fractional Mode	Normalized to 1 Hz		-227		dBc/Hz
Flicker (Both Modes)	Normalized to 1 Hz		-268		dBc/Hz
VCO Characteristics					
VCO Tuning Sensitivity at 2800 MHz	Measured at 2.5 V		13.3		MHz/V
VCO Tuning Sensitivity at 2400 MHz	Measured at 2.5 V		13.8		MHz/V
VCO Tuning Sensitivity at 2000 MHz	Measured at 2.5 V		13.6		MHz/V
VCO Tuning Sensitivity at 1600 MHz	Measured at 2.5 V		12.1		MHz/V
VCO Supply Pushing	Measured at 2.5 V		2		MHz/V

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.





Figure 1. Typical Closed Loop Integer Phase Noise ["Loop Filter Configuration Table"]

v03.0512

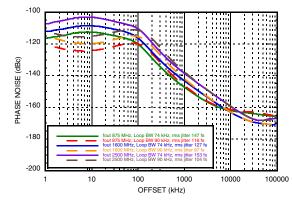


Figure 3. Free Running Phase Noise

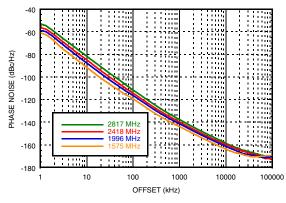


Figure 5. Typical VCO Sensitivity

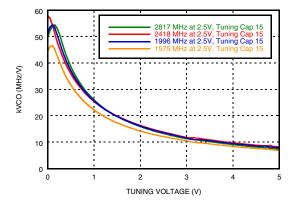


Figure 2. Typical Closed Loop Fractional

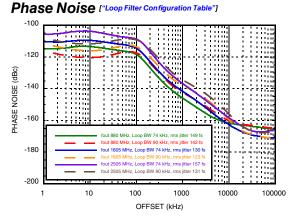


Figure 4. Free Running VCO Phase Noise vs. Temperature

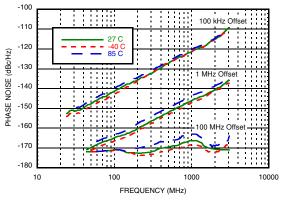
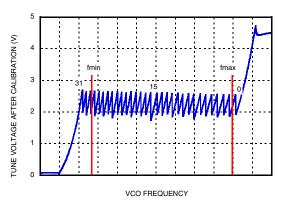


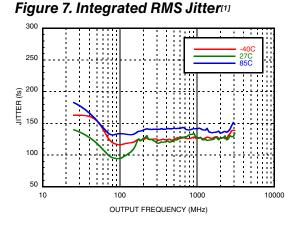
Figure 6. Typical Tuning Voltage After Calibration



Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.







v03.0512

Figure 9. Typical Output Power

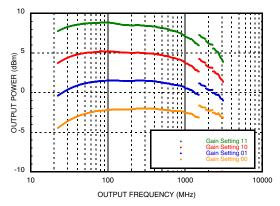


Figure 11. RF Output Return Loss

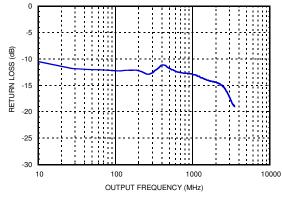


Figure 8. Figure of Merit

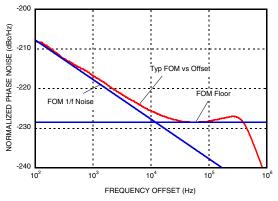
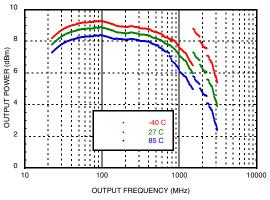
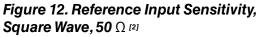
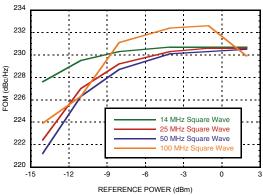


Figure 10. Typical Output Power vs. Temperature, Maximum Gain







[1] RMS Jitter data is measured in fractional mode with 100 kHz Loop bandwidth using 50 MHz reference frequency from 1 kHz to 20 MHz integration bandwidth.

[2] Measured from a 50 Ω source with a 100 Ω external resistor termination. See <u>PLL with Integrated RF VCOs Operating Guide</u> Reference Input Stage section for more details. Full FOM performance up to maximum 3.3 Vpp input voltage.

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.





Figure 13. Reference Input Sensitivity Sinusoid Wave, 50 $\Omega^{[3]}$

v03.0512

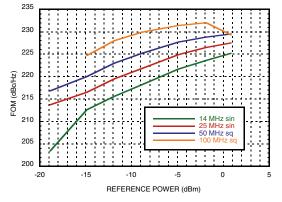
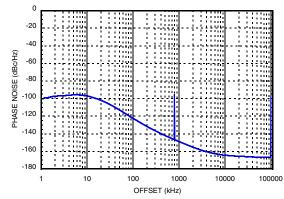
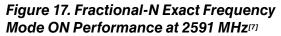


Figure 15. Integer-N Exact Frequency Mode ON Performance at 704 MHz^[5]





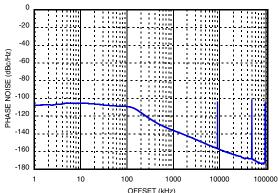


Figure 14. Integer Boundary Spur at 2500.2 MHz^[4]

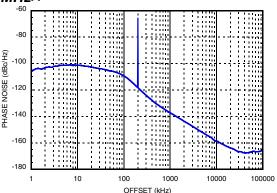


Figure 16. Fractional-N Exact Frequency Mode ON Performance at 2113.5 MHz^[6]

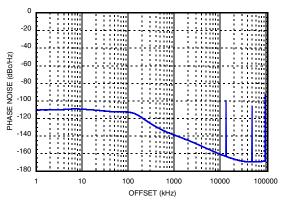
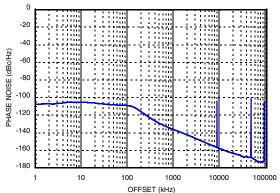


Figure 18. Fractional-N Exact Frequency Mode OFF Performance at 2591 MHz^[8]



[3] Measured from a 50 Ω source with a 100 Ω external resistor termination. See PLL with Integrated RF VCOs Operating Guide Reference Input Stage section for more details. Full FOM performance up to maximum 3.3 Vpp input voltage.

[4] Fractional Mode in Mode B, Integer Boundary at 2500 MHz

[5] REF in = 100 MHz, PD = 800 kHz, Output Divider 4 Selected, Loop Filter bandwidth = 16 kHz, Channel Spacing 200 kHz

[6] Exact Frequency Mode, REF in = 100 MHz, PD = 50 MHz, Output Divider 1 Selected, Loop Filter bandwidth = 100 kHz, Channel Spacing = 100 kHz
 [7] Exact Frequency Mode, Channel Spacing = 100 kHz, Fractional Mode B RF out = 2591 MHz, REF in = 100 MHz, PD frequency = 50 MHz, Output Divider 1 selected, Loop Filter bandwidth = 120 kHz,

[8] Fractional Mode B RF out = 2591 MHz, REF in = 100 MHz, PD frequency = 50 MHz, Output Divider 1 selected, Loop Filter bandwidth = 120 kHz.

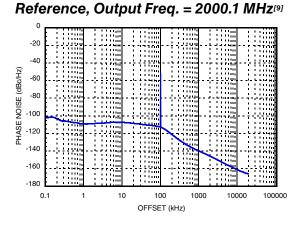
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.



ROHS V

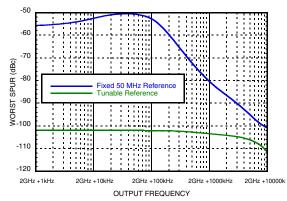
FRACTIONAL-N PLL WITH INTEGRATED VCO 25 - 3000 MHz





v03.0512

Figure 21. Worst Spur, Fixed vs. Tunable Reference [10]



Loop Filter Configuration Table

Figure 20. Worst Spur, Tunable Reference, Output Frequency = 2000.1 MHz [9]

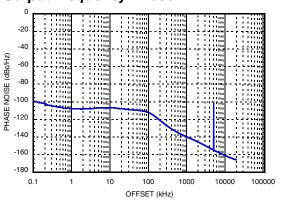
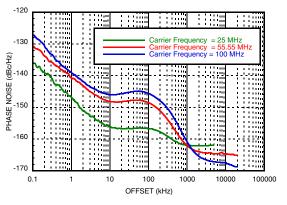


Figure 22. Low Frequency Performance [11]



Loop Filter BW (kHz)	C1 (pF)	C2 (nF)	C3 (pF)	C4 (pF)	R2 (kΩ)	R3 (kΩ)	R4 (kΩ)	Loop Filter Design
74	150	27	220	220	0.82	1	1	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$
90	270	3.9	56	56	1.2	1	1	

[9] Capability of HMC830LP6GE to generate low frequencies (as low as 25 MHz), enables the HMC830LP6GE to be used as a tunable reference source into another HMC830LP6GE, which maximizes spur performance of the second HMC830LP6GE. Please see <u>"HMC830LP6GE</u> <u>Application Information</u>" for more information.

[10] The graph is generated by observing, and plotting, the magnitude of only the worst spur (largest magnitude), at any offset, at each output frequency, while using a fixed 50 MHz reference and a tunable reference tuned to 47.5 MHz. See <u>"HMC830LP6GE Application Information"</u> for more details.

[11] Phase noise performance of the HMC830LP6GE when used as a tunable reference source. HMC830LP6GE is operating at 3 GHz/30, 3 GHz/54, and 1.55 GHz/62 for the 100 MHz, 55.55 MHz, and 25 MHz curves respectively. 25 MHz output is 50 MHz low pass filtered prior to input to second PLL. 100 MHz and 55.55 MHz curves were not filtered.

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.



v03.0512

HMC830LP6GE



FRACTIONAL-N PLL WITH INTEGRATED VCO 25 - 3000 MHz

Pin Descriptions

Pin Number	Function	Description	
1	AVDD	DC Power Supply for analog circuitry.	
2, 5, 6, 8, 9, 11 - 14, 18 - 22, 24, 26, 34, 37, 38	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
3	VPPCP	Power Supply for charge pump analog section	
4	СР	Charge Pump Output	
7	VDDLS	Power Supply for the charge pump digital section	
10	RVDD	Reference Supply	
15	XREFP	Reference Oscillator Input	
16	DVDD3V	DC Power Supply for Digital (CMOS) Circuitry	
17	CEN	Chip Enable. Connect to logic high for normal operation.	
23	VTUNE	VCO Varactor. Tuning Port Input.	
25	VCC2	VCO Analog Supply 2	
27	VCC1	VCO Analog Supply 1	
28	RF_N	RF Negative Output (On in differential configuration, On in single-ended configuration)	
29	RF_P	RF Positive Output (On in differential configuration, Off in single-ended configuration)	
30	SEN	PLL Serial Port Enable (CMOS) Logic Input	
31	SDI	PLL Serial Port Data (CMOS) Logic Input	
32	SCK	PLL Serial Port Clock (CMOS) Logic Input	
33	LD_SDO	Lock Detect, or Serial Data, or General Purpose (CMOS) Logic Output (GPO)	
35	VCCHF	DC Power Supply for Analog Circuitry	
36	VCCPS	DC Power Supply for Analog Prescaler	
39	VCCPD	DC Power Supply for Phase Detector	
40	BIAS	External bypass decoupling for precision bias circuits. Note: 1.920V ±20mV reference voltage (BIAS) is generated internally and canno drive an external load. Must be measured with 10GΩ meter such as Agilent 34410 normal 10MΩ DVM will read erroneously.	

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.





FRACTIONAL-N PLL WITH INTEGRATED VCO 25 - 3000 MHz

Absolute Maximum Ratings

-0.3 V to +3.6 V
-0.3 V to +5.5 V
-0.3 V to +5.5 V
-40 °C to +85 °C
-65 °C to 150 °C
150 °C
9 °C/W
260 °C
40 sec
Class 1B

v03.0512

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Condition	Min.	Тур.	Max.	Units
Temperature					
Junction Temperature				125	°C
Ambient Temperature		-40		85	°C
Supply Voltage					
AVDD, RVDD, DVDD3V, VCCPD, VCCHF, VCCPS		3.0	3.3	3.5	v
VPPCP, VDDLS, VCC1, VCC2		4.8	5	5.2	V

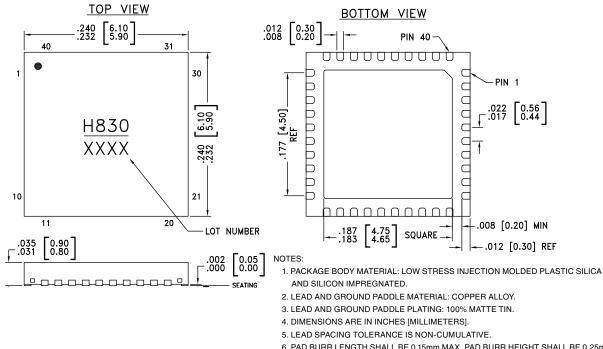
[1] Layout design guidelines set out in Qualification Test Report are strongly recommended.

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent or rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.





Outline Drawing



v03.0512

6. PAD BURR LENGTH SHALL BE 0.15mm MAX. PAD BURR HEIGHT SHALL BE 0.25mm MAX.

7. PACKAGE WARP SHALL NOT EXCEED 0.05mm.

8. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

9. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED PCB LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[1]
HMC830LP6GE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1	<u>H830</u> XXXX

[1] 4-Digit lot number XXXX

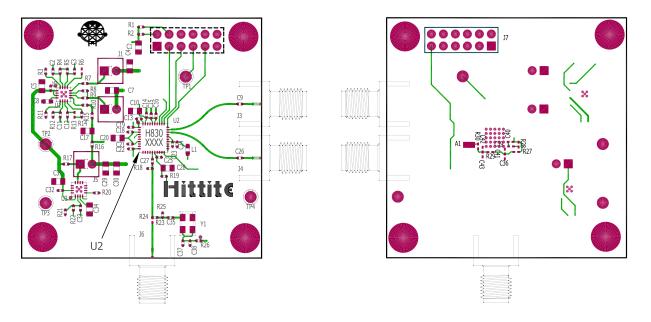
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.





FRACTIONAL-N PLL WITH INTEGRATED VCO 25 - 3000 MHz

Evaluation PCB



v03.0512

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

Evaluation PCB Schematic

To view this <u>Evaluation PCB Schematic</u> please visit <u>www.hittite.com</u> and choose HMC830LP6GE from the "Search by Part Number" pull down menu to view the product splash page.

Evaluation Order Information

Item	Contents	Part Number
Evaluation PCB Only	HMC830LP6GE Evaluation PCB	EVAL01-HMC830LP6GE
Evaluation Kit	HMC830LP6GE Evaluation PCB USB Interface Board 6' USB A Male to USB B Female Cable CD ROM (Contains User Manual, Evaluation PCB Schematic, Evaluation Software, Hittite PLL Design Software)	EKIT01-HMC830LP6GE

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.





HMC830LP6GE Application Information

v03.0512

Large bandwidth (25 MHz to 3000 MHz), industry leading phase noise and spurious performance, excellent noise floor (<-170 dBc/Hz), coupled with a high level of integration make the HMC830LP6GE ideal for a variety of applications; as an RF or IF stage LO, a clock source for high-frequency data-converters, or a tunable reference source for extremely low spurious applications (< -100 dBc/Hz spurs).

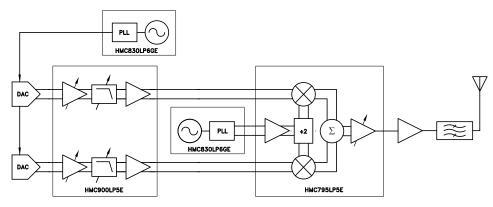


Figure 23. HMC830LP6GE in a typical transmit chain

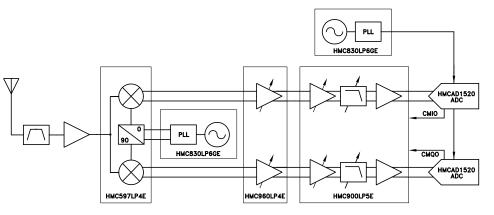


Figure 24. HMC830LP6GE in a typical receive chain

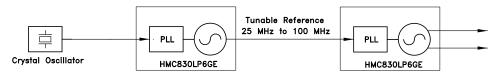


Figure 25. HMC830LP6GE used as a tunable reference for second HMC830LP6GE

Using the HMC830LP6GE with a tunable reference as shown in Figure 25, it is possible to drastically improve spurious emissions performance across all frequencies. Example shown in Figure 21 graph shows that it is possible to have spurious emissions < -100 dBc/Hz across all frequencies. For more information about spurious emissions, how they are related to the reference frequency, and how to tune the reference frequency for optimal spurious performance please see the "Spurious Performance" section of <u>Hittite PLL w/ Integraged VCOs Operating Guide</u>. Note that at very low output frequencies < 100 MHz, harmonics increase due to small internal AC coupling. Applications which are sensitive to harmonics may require external low pass filtering.

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.



v03.0512

HMC830LP6GE



FRACTIONAL-N PLL WITH INTEGRATED VCO 25 - 3000 MHz

Notes:

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.